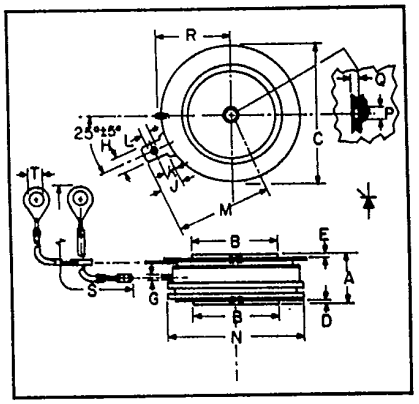
POWEREX

C430__X550

Phase Control SCR

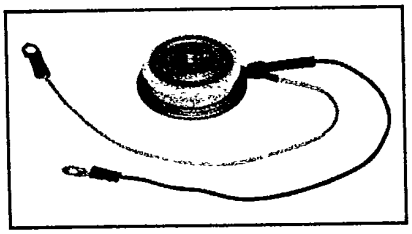
800 Amperes Avg
100-400 Volts

Powerex, Inc. Hillis Street, Youngwood, Pennsylvania 15697 (412) 925-7272
Powerex Europe, S.A., 428 Ave. G. Durand, BP107, 72003 LeMans, France (43) 72.75.15



C430__X550
Outline Drawing

Dimensions	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	.560	.605	14.22	15.37
B	.985	.995	25.01	25.27
C	1.600	1.650	40.64	41.91
D	.030	—	.76	—
E	.040	—	1.01	—
G	.057	.059	1.44	1.50
H	.186	.191	4.72	4.85
J	.245	.255	6.22	6.48
K	.115	.130	2.92	3.30
L	.064	.070	1.62	1.78
M	—	1.120	—	28.45
N	—	1.585	—	40.26
P	.135	.145	3.42	3.68
Q	.070	.084	1.77	2.13
R	—	.875	—	22.23
S	12.219	12.343	310.36	313.51
T	.137	.153	3.47	3.89



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Description
Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak (Pow-R-Disc) devices employing the field-proven amplifying (di/namic) gate.

Features:
- ☐ Low On-State Voltage
- ☐ High di/dt
- ☐ High dv/dt
- ☐ Hermetic Packaging
- ☐ Excellent Surge and I^2t Ratings
- ☐ High Temperature Operation

Applications:
- ☐ Power Supplies
- ☐ Battery Chargers
- ☐ Motor Control
- ☐ Light Dimmers
- ☐ VAR Generators

Ordering Information
Example: Select the complete nine digit part number you desire from the table – i.e. C430DX550 is a 400 Volt, 800 Ampere Phase Control SCR.

Type	Voltage		Current
	V_{DRM} V_{RRM}	Code	I_T (avg)
C430__X550	100	A	800
	200	B	
	300	C	
	400	D	

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Absolute Maximum Ratings

	Symbol	C430__X550	Units
RMS On-State Current	$I_{T(RMS)}$	1250	Amperes
Average On-State Current	$I_{T(av)}$	800	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}	9000	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}	8200	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	400	Amperes/μs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	150	Amperes/μs
I^2t (for Fusing), One Cycle at 60Hz	I^2t	335,000	A^2sec
Peak Gate Power Dissipation	P_{GM}	200	Watts
Average Gate Power Dissipation	$P_{G(av)}$	5	Watts
Storage Temperature	T_{STG}	−40 to 150	°C
Operating Temperature	T_J	−40 to 150	°C
Mounting Force①		800 to 2200	lb.
Mounting Force①		3.6 to 11.1	kN

① Consult recommended mounting procedures.

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Electrical and Thermal Characteristics

Characteristics	Symbol	Test Conditions	C430__X550	Units
Voltage—Blocking State Maximums				
Forward Leakage, Peak	I_{DRM}	T_J = 25°C, V = V_{DRM}	50	mA
Reverse Leakage, Peak	I_{RRM}	T_J = 25°C, V = V_{RRM}	50	mA
Current—Conducting State Maximums				
Peak On-State Voltage	V_{TM}	I_{TM} = 3000A, T_C = 25°C	1.9	Volts
Switching				
Typical Turn-Off Time	t_q	T_J = 150°C; I_{TM} = 500A, V_R = 50V Min; V_{DRM} (Reapplied); Reapplied dv/dt = 20V/µsec (linear); Commutation di/dt = 25A/µsec; Repetition Rate = 1pps, Gate Bias during Turn-Off interval = 0V, 100Ω	125	µsec
Typical Delay Time	t_d	T_C = 25°C, I_T = 50Adc, Gate Supply: 20V, 20Ω, 0.1µsec Rise Time	0.7	µsec
Min. Critical dv/dt exponential to V_{DRM}	dv/dt	T_J = 150°C, V_{DRM} rated, gate open	100	V/µsec
Thermal and Mechanical				
Maximum Thermal Resistance,① double sided cooling				
Junction to Case (2000 lb. force)	$R_{\theta JC}$		.04	°C/Watt
Case to Sink, Lubricated (2000 lb. force)	$R_{\theta CS}$		.02	°C/Watt
Gate—Maximum Parameters				
Gate Current to Trigger	I_{GT}	V_D = 6V, T_J = 150°C, R_L = 3 ohms	100	mA
Gate Voltage to Trigger	V_{GT}	V_D = 6V, T_J = 150°C, R_L = 3 ohms	5	Volts
Non-Triggering Gate Voltage	V_{GDM}	T_J = 150°C, rated V_{DRM}	.15	Volts
Peak Forward Gate Current	I_{GTM}		4	Amperes
Peak Reverse Gate Voltage	V_{GRM}		5	Volts

① Consult recommended mounting procedures.

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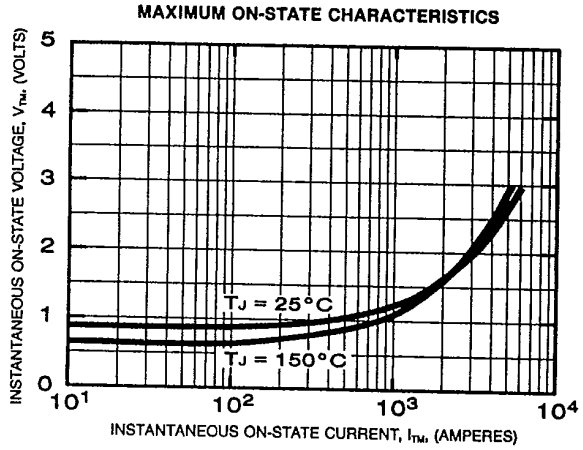
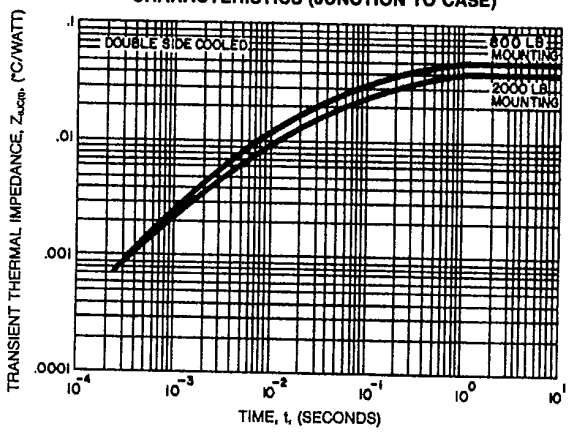
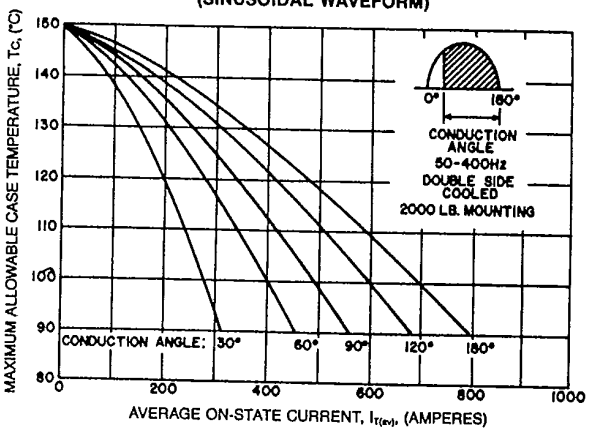
MAXIMUM ON-STATE CHARACTERISTICS



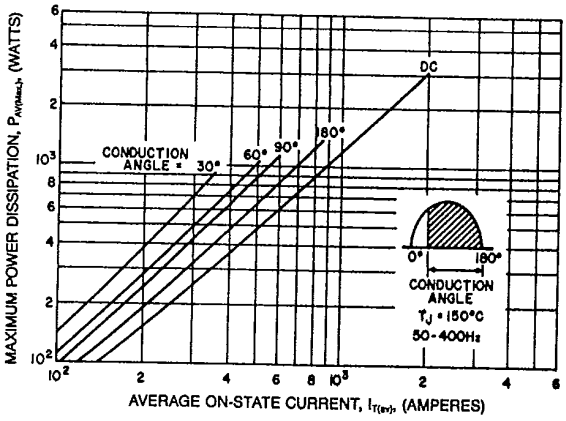
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



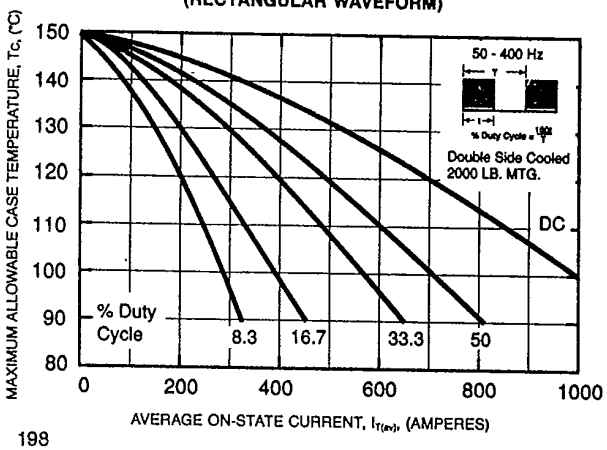
MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



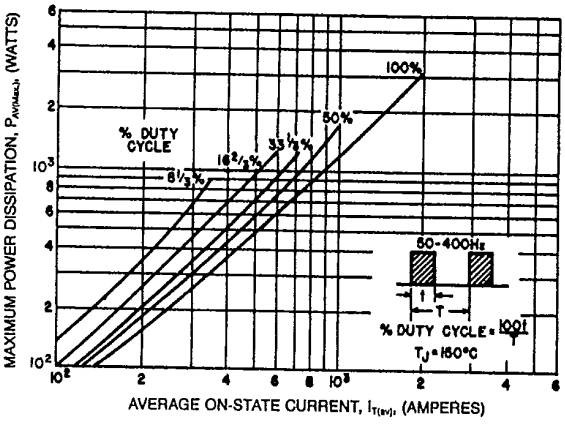
MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM)



MAXIMUM ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)



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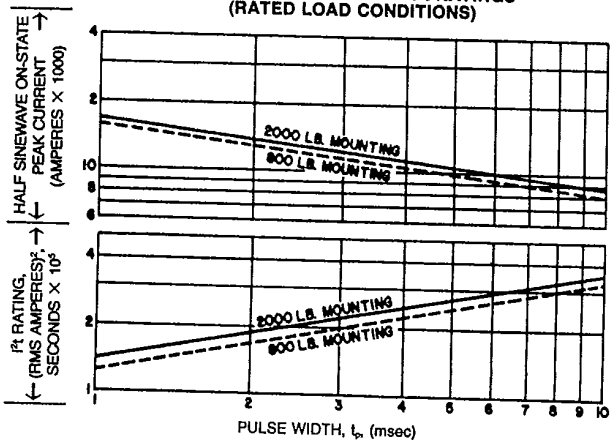
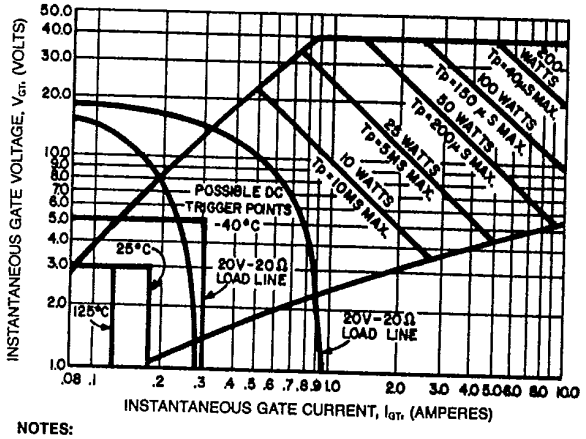
SUB-CYCLE SURGE AND I^2t RATINGS (RATED LOAD CONDITIONS)



GATE CHARACTERISTICS



NOTES:
1. Maximum allowable average gate dissipation = 5 watts.
2. The locus of possible dc trigger points lie outside the boundaries shown at various case temperatures.
3. Tp = Rectangular gate current pulse width (5µs min. duration; 1.0µs max. rise time for 20V, 65Ω source).
4. 20V – 20Ω is the minimum gate source load line when rate of circuit current rise > 100 Amp/µs or anode rate of current rise > 200 Amps/µs (Tp = 5µs min., 0.5µs max. rise time).

   Maximum long-term repetitive anode di/dt = 500 Amps/µs with 20V – 20Ω gate source.